

RoHS

COMPLIANT

**Vishay Siliconix** 

# P-Channel 20-V (D-S) MOSFET

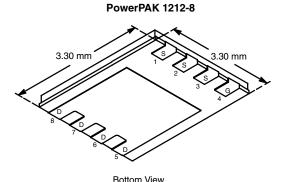
PRODUCT SUMMARY					
V <sub>DS</sub> (V)	r <sub>DS(on)</sub> (Ω)	I <sub>D</sub> (A)			
	0.021 at $V_{GS} = -4.5 \text{ V}$	- 11			
-20	0.028 at $V_{GS} = -2.5 \text{ V}$	- 9.8			
	0.034 at $V_{GS} = -1.8$ V	- 8.9			

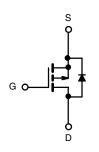
### **FEATURES**

- TrenchFET<sup>®</sup> Power MOSFETS: 1.8-V Rated
- New PowerPAK<sup>®</sup> Package
  - Low Thermal Resistance, R<sub>thJC</sub>
- Low 1.07-mm Profile

#### **APPLICATIONS**

- · Load/Power Switching In Cell Phones and Pagers
- PA Switch for Cellular Devices
- Battery Operated Systems





P-Channel MOSFET

Ordering Information: Si7401DN-T1 Si7401DN-T1–E3 (Lead (Pb)–free)

ABSOLUTE MAXIMUM RATINGS	$T_A = 25 \ ^{\circ}C$ , unless otherwise noted
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Parameter		Symbol	10 secs	Steady State	Unit
Drain-Source Voltage		V <sub>DS</sub>	- 20		V
Gate-Source Voltage		V <sub>GS</sub>	± 8		
	<sub>A</sub> = 25 °C		- 11	- 7.3	А
$T_{A}$	<sub>A</sub> = 85 °C		- 8.2	- 5.2	
Pulsed Drain Current		I <sub>DM</sub>	- 30		A
Continuous Source Current (Diode Conduction) <sup>a</sup>		۱ <sub>S</sub>	- 3.2	– 1.3	
Maximum Davian Disainational	<sub>A</sub> = 25 °C	P <sub>n</sub>	3.8	1.5	W
Maximum Power Dissipation <sup>a</sup>	<sub>A</sub> = 85 °C		2.0	0.8	
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	– 55 to 150		°C
Soldering Recommendations <sup>b,c</sup>			260		

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Typical	Maximum	Unit
	$t \le 10$ sec	R <sub>thJA</sub>	26	33	°C/W
Maximum Junction-to-Ambient <sup>a</sup>	Steady State		65	81	
Maximum Junction-to-Case	Steady State	R <sub>thJC</sub>	1.9	2.4	

Notes

a. Surface Mounted on 1" x 1" FR4 Board.

b. See Solder Profile (http://www.vishay.com/ppg?73257). The PowerPAK 1212-8 is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.

c. Rework Conditions: manual soldering with a soldering iron is not recommended for leadless components.

\* Pb containing terminations are not RoHS compliant, exemptions may apply

Document Number: 71423 S-51210-Rev. B, 27-Jun-05

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<b>SPECIFICATIONS</b> T <sub>J</sub> = 25 °C, unless otherwise noted								
Parameter	Symbol	Test Condition Min		Тур	Max	Unit		
Static		-		•	•			
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_D = -2 \text{ mA}$	- 0.45		- 1.0	V		
Gate-Body Leakage	I <sub>GSS</sub>	$V_{DS} = 0 V$ , $V_{GS} = \pm 8 V$			± 100	nA		
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	$V_{DS} = -20 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$ - 1			- 1			
		$V_{DS} = -20 \text{ V}, \text{ V}_{GS} = 0 \text{ V}, \text{ T}_{J} = 85 ^{\circ}\text{C}$			- 5	μA		
On-State Drain Current <sup>a</sup>	I <sub>D(on)</sub>	$V_{DS} \leq -5$ V, $V_{GS} = -4.5$ V	- 30			A		
	r <sub>DS(on)</sub>	$V_{GS} = -4.5 \text{ V}, \text{ I}_{D} = -11 \text{ A}$		0.017	0.021	Ω		
Drain-Source On-State Resistance <sup>a</sup>		$V_{GS} = -2.5 \text{ V}, \text{ I}_{D} = -9.8 \text{ A}$		0.022	0.028			
		$V_{GS} = -1.8 \text{ V}, I_D = -2 \text{ A}$		0.027	0.034			
Forward Transconductance <sup>a</sup>	9 <sub>fs</sub>	V <sub>DS</sub> = - 15 V, I <sub>D</sub> = - 11 A		31		S		
Diode Forward Voltage <sup>a</sup>	V <sub>SD</sub>	$I_{S} = -3.2 \text{ A}, V_{GS} = 0 \text{ V}$		- 0.8	- 1.2	V		
Dynamic <sup>b</sup>								
Total Gate Charge	Qg			29	44			
Gate-Source Charge	Q <sub>gs</sub>	$V_{DS} = -10 \text{ V}, V_{GS} = -4.5 \text{ V}, I_{D} = -11 \text{ A}$		5.9		nC		
Gate-Drain Charge	Q <sub>gd</sub>			5.2				
Turn-On Delay Time	t <sub>d(on)</sub>			23	35			
Rise Time	t <sub>r</sub>	$V_{DD}$ = $-$ 10 V, $R_L$ = 10 $\Omega$		45	70			
Turn-Off DelayTime	t <sub>d(off)</sub>	$I_{D}{\cong}{=}1$ A, $V_{GEN}{=}{-}4.5$ V, $R_{G}{=}6~\Omega$		130	195	ns		
Fall Time	t <sub>f</sub>			95	140			
Source-Drain Reverse Recovery Time	t <sub>rr</sub>	$I_F = -3.2 \text{ A}, \text{ di/dt} = 100 \text{ A/}\mu\text{s}$		30	60			

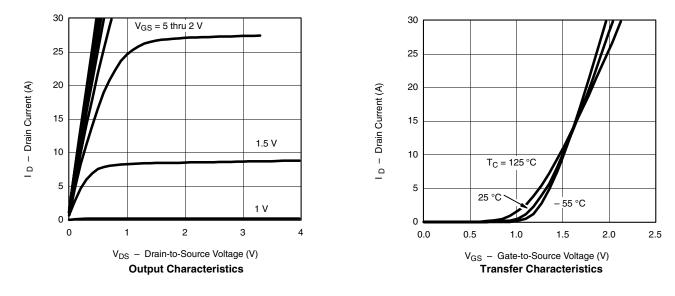
Notes

a. Pulse test; pulse width  $\leq$  300 µs, duty cycle  $\leq$  2 %.

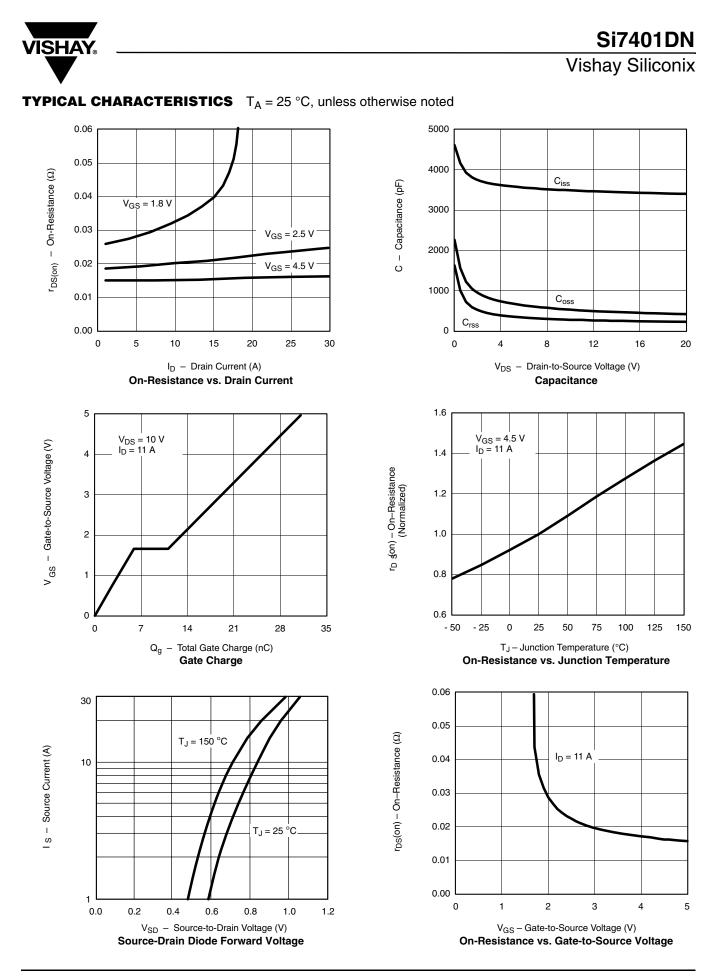
b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

**TYPICAL CHARACTERISTICS**  $T_A = 25 \text{ °C}$ , unless otherwise noted



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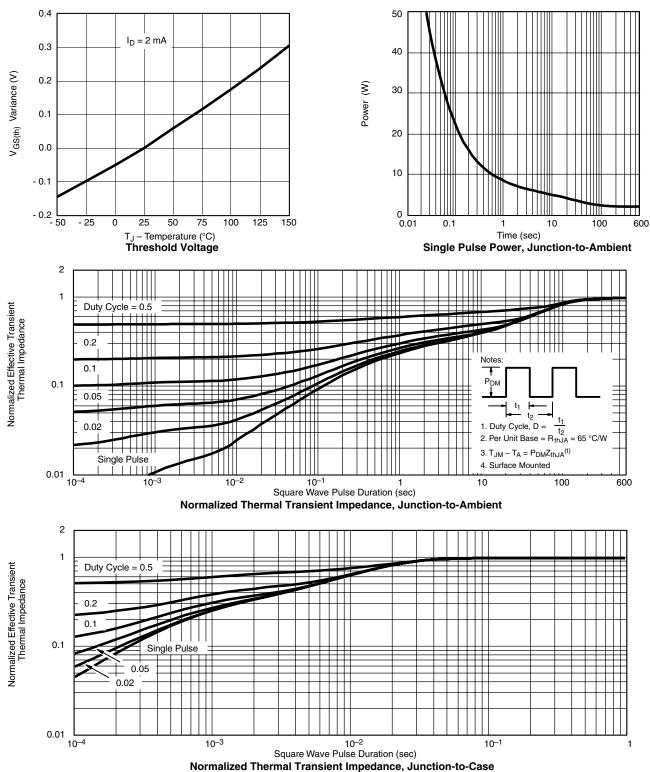


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# Si7401DN

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Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see http://www.vishay.com/ppg?71423.

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